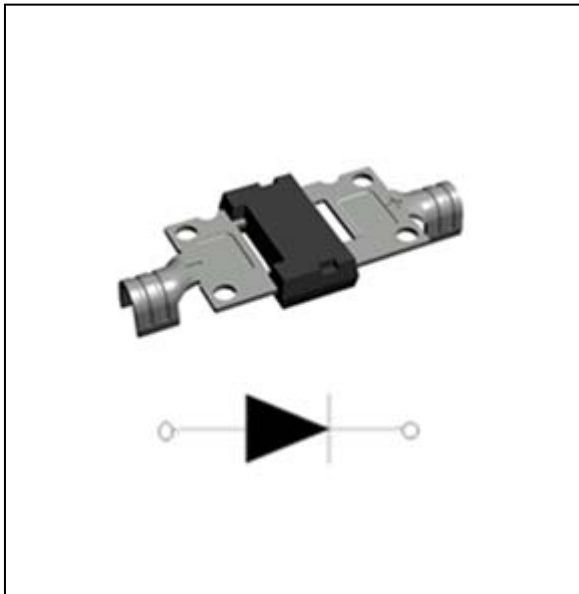




# GFMK3045P

## Schottky Bypass Diode Module



### Features

- High frequency operation
- Low forward voltage drop
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability

### Typical Applications

Photovoltaic solar cell protection schottky rectifier

### Mechanical Data

**Package:** GF025

Molding compound meets UL 94 V-0 flammability rating,

**Terminals:** Tin plated leads, solderable per J-STD-002 and JESD 22-B102

**Polarity:** As marked

### Maximum Ratings ( $T_a=25$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	GFMK3045P
Device marking code			GFMK3045P
Repetitive Peak Reverse Voltage	VRRM	V	45
Average Rectified Output Current @60Hz sine wave, R-load, $T_a=25$	I <sub>O</sub>	A	30
Surge(Non-repetitive)Forward Current @60Hz sine wave, 1 cycle, $T_j=25$	I <sub>FSM</sub>	A	350
Current Squared Time @1ms $t < 8.3ms$ $T_j=25$ , Rating of per diode	I <sup>2</sup> t	A <sup>2</sup> S	505
Storage Temperature	T <sub>stg</sub>		-55 ~+150
Junction Temperature IN DC Forward Mode-Forward Operations without reverse bias, t 1 h (Fig. 1) 1	T <sub>j</sub>		-55 ~+200

#### Note

(1) Meets the requirements of IEC 61215 Ed. 2 bypass diode thermal test.

### Electrical Characteristics ( $T_a=25$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	TEST CONDITIONS	GFMK3045P
Maximum instantaneous forward voltage drop per diode	V <sub>F</sub>	V	I <sub>FM</sub> =30A	0.55
Maximum DC reverse current at rated DC blocking voltage per diode	I <sub>RRM</sub>	μA	V <sub>RM</sub> =VRRM	200

### Thermal Characteristics ( $T_a=25$ Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	GFMK3045P
Thermal Resistance 1	R <sub>J-C</sub>	/W	1.5

#### Note

(1) Thermal resistance from Between junction and case, On glass-epoxi substrate.



# GFMK3045P

## Ordering Information (Example)

PREFERRED P/N	UNIT WEIGHT(g)	MINIMUM PACKAGE(pcs)	INNER BOX QUANTITY(pcs)	OUTER CARTON QUANTITY(pcs)	DELIVERY MODE
GFMK3045P	Approximate 4.0	30	600	2400	Tube

## Characteristics (Typical)

FIG1:Io -Tc Curve

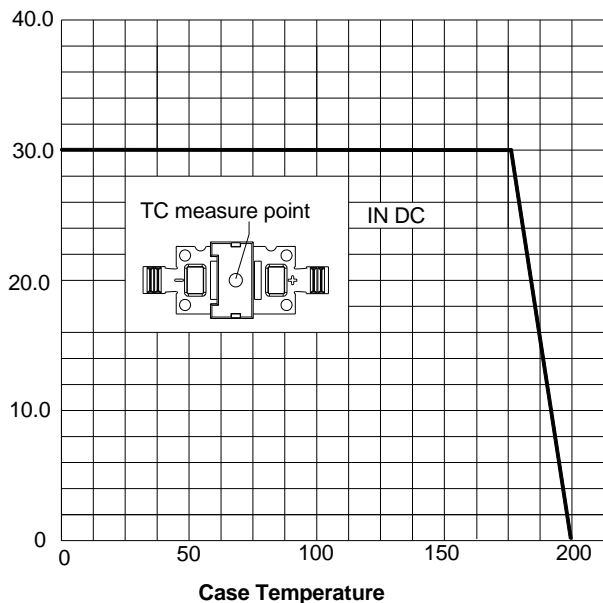


FIG2:Surge Forward Current Capability

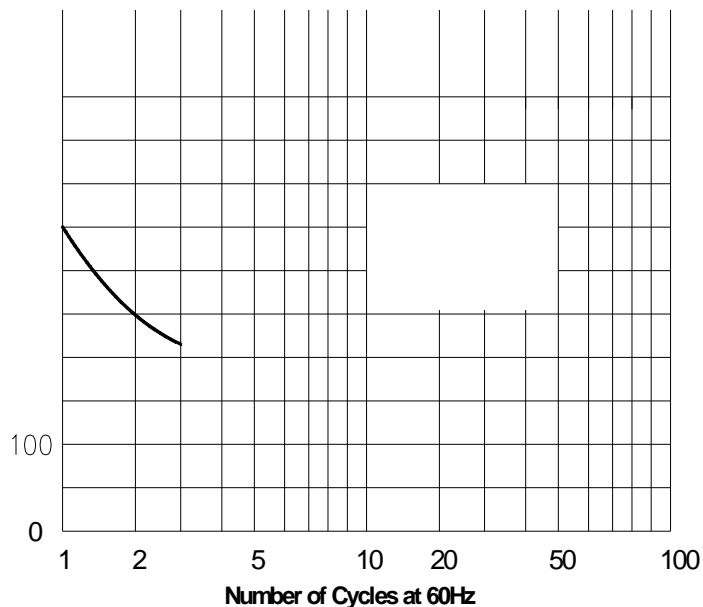


FIG3:Instantaneous Forward Voltage

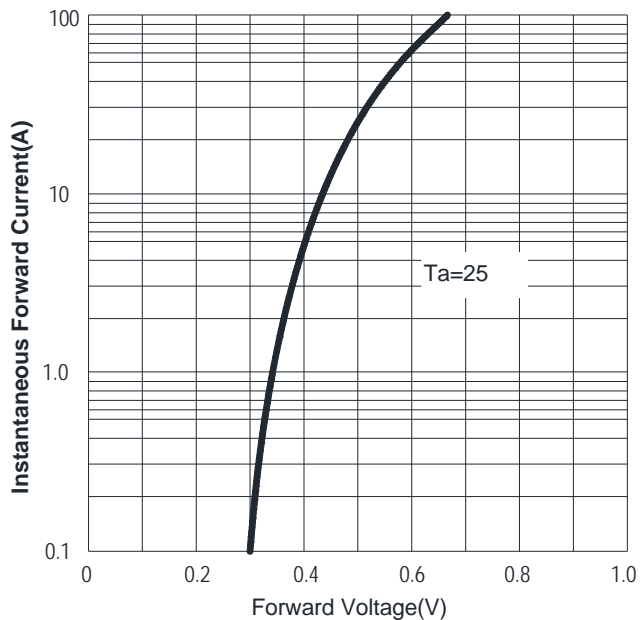
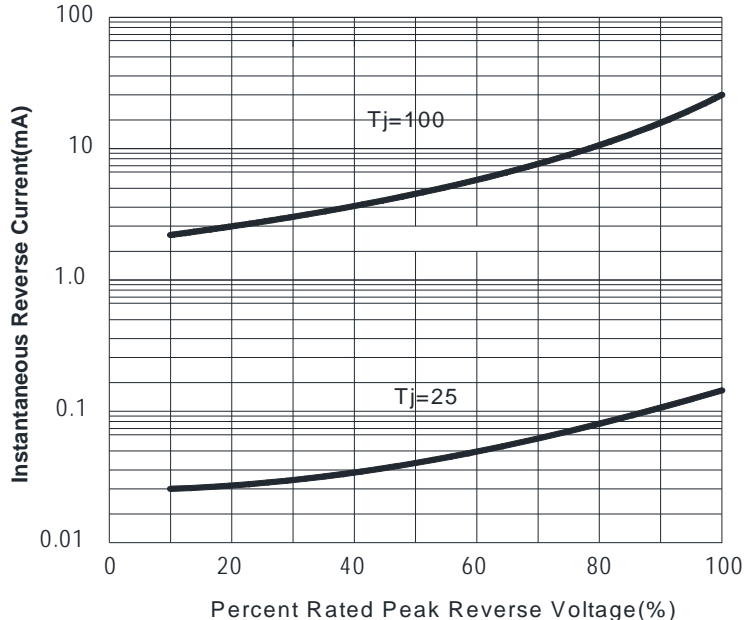
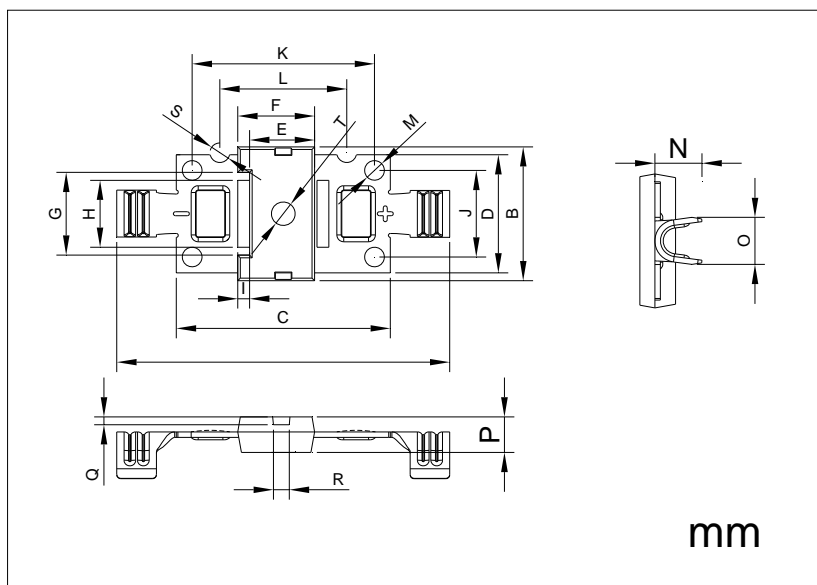


FIG4:Instantaneous Reverse Characteristics



## Outline Dimensions (in millimeters)



DIM	MM		NOTE
	MIN	MAX	
A	41.5	42.5	
B	16.5	17.5	
C	26.5	27.5	
D	14.5	15.5	
E	7.9	8.5	
F	9.4	10	
G	10.50REF		
H	8.2	8.8	
I	1.2	1.8	
J	10.7	11.3	
K	22.7	23.3	
L	15.7	16.3	
M	2.	2.	
N	5.65	6.25	
O	5.72	6.22	
P	4.4	4.6	
Q	0.7	1.3	
R	1.7	2.3	
S	2.	2.	
T	2.	3.	



## GFMK3045P

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